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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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SANYO Semiconductors DATA SHEET

FW812 — General-Purpose Switching Device

Applications

Features

- · Low ON-resistance
- · 4V drive
- · Composite type with 2 MOSFETs contained in a single package, facilitating high-density mounting

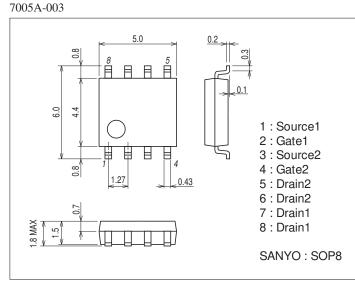
Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		35	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		10	Α
Drain Current (PW=10s)	ID	Duty cycle≤1%	11.5	Α
Drain Current (PW≤10μs)	IDP	Duty cycle≤1%	52	Α
Allowable Power Dissipation	PD	When mounted on ceramic substrate (2000mm²x0.8mm) 1unit, PW≤10s	2.3	W
Total Dissipation	PT	When mounted on ceramic substrate (2000mm ² ×0.8mm), PW≤10s	2.5	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Package Dimensions

unit: mm (typ)

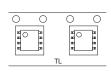


Product & Package Information

• Package : SOP8

JEITA, JEDEC : SC-87, SOT96
 Minimum Packing Quantity : 1,000 pcs./reel

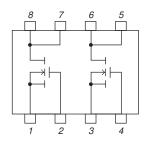
Packing Type: TL



Marking



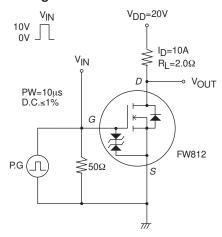
Electrical Connection

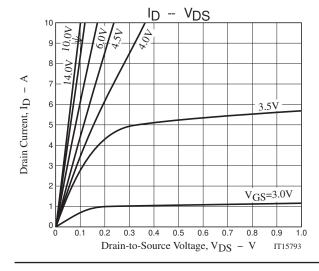


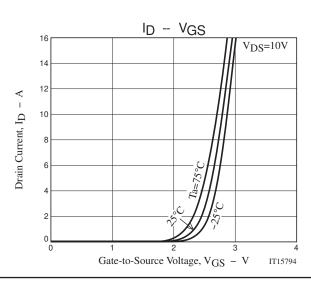
Electrical Characteristics at Ta=25°C

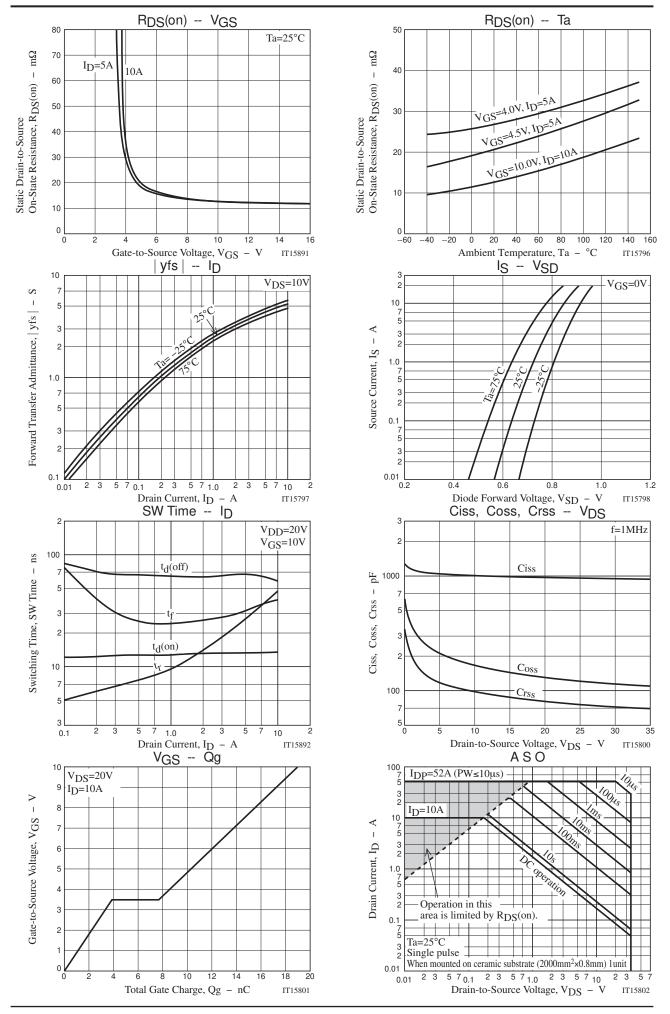
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Uniit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	35			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =35V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	V _{GS} (off)	V _{DS} =10V, I _D =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =10A		5.2		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =10A, V _{GS} =10V		13	17	mΩ
	R _{DS} (on)2	I _D =5A, V _{GS} =4.5V		21	30	mΩ
	R _{DS} (on)3	I _D =5A, V _{GS} =4V		27	38	mΩ
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		960		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		130		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		80		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		13.5		ns
Rise Time	tr	See specified Test Circuit.		46.6		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		57.0		ns
Fall Time	tf	See specified Test Circuit.		38.9		ns
Total Gate Charge	Qg	V _{DS} =20V, V _{GS} =10V, I _D =10A		19		nC
Gate-to-Source Charge	Qgs	V _{DS} =20V, V _{GS} =10V, I _D =10A		3.9		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =20V, V _{GS} =10V, I _D =10A		3.8		nC
Diode Forward Voltage	V _{SD}	I _S =10A, V _{GS} =0V		0.85	1.2	V

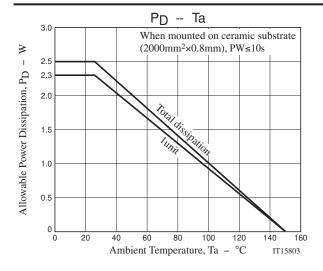
Switching Time Test Circuit

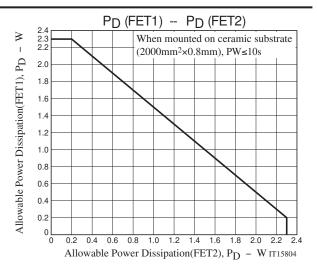












Note on usage: Since the FW812 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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